

*Concluded B1*

a source-drain wiring layer electrically connected to said source-drain region;  
 and  
 a gate wiring layer electrically connected to said gate electrode,  
 at least one of the component parts being formed from a conductive film or a  
 semiconductor film [and being provided] with a [radiating] heat dissipating extension  
 [extending outwardly from the at least one component part].

Claim 2, line 2, change "radiating" to --heat dissipating--.

Claim 3, line 2, change "radiating" to --heat dissipating--.

Claim 4, line 2, change "radiating" to --heat dissipating--.

Claim 5, line 2, change "radiating" to --heat dissipating--.

Claim 6, line 2, change "radiating" to --heat dissipating--.

Claim 7, line 2, change "radiating" to --heat dissipating--.

Claim 8, line 2, change "radiating" to --heat dissipating--.

*B2 c*

9. (Amended) The thin film transistor according to claim [7] ~~8~~, wherein said  
 [radiating] heat dissipating extension extends from both sides of said source-drain region.

Claim 10, line 3, change "radiating" to --heat dissipating--.

Claim 11, line 2, change "radiating" to --heat dissipating--.

Claim 12, line 2, change "radiating" to --heat dissipating--; and

line 3, change "radiating" to --heat dissipating--.

Claim 13, line 2, change "radiating" to --heat dissipating--.

Claim 14, line 2, change "radiating" to --heat dissipating--.

Claim 17, line 2, change "radiating" to --heat dissipating--.

Claim 20, line 2, change "radiating" to --heat dissipating--.

Claim 21, line 2, change "radiating" to --heat dissipating--.